NSN 5961-01-062-0663

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-062-0663 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches Overall Diameter: Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage, dc and 40.0 collector to emitter voltage/static/base open and 12.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 375.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-1130 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: